

RF Power Amplifier module

AP20002500-2

This solid state power amplifier is designed for reliable, trouble-free service. It operates in a class A with a 12 V DC power supply. The amplifier is accommodated in aluminium housing.

Features :

- * 4 Watts saturated output power
- * 33 dB minimum gain
- * Electronic Attenuator in option
- * Overvoltage and reverse protection

Applications :

- * RF links
- * Test Bench
- * Field Test
- * Instrumentation

case B016-01

Specifications

Characteristics	Data	Units
Frequency range	2000 MHz - 2500 MHz	MHz
RF output power CW		
Typ.	3	W
Min	2	W
Class	A	
Power gain	33	dB
Flatness	+/- 2 dB	dB
Input power for rated output power	0	dBm
Max. input power	10	dBm
In / Out impedances nom.	50	Ohms
Input VSWR	2 : 1	
Load VSWR for rated output power	up to 1.5 : 1	
VSWR mismatch	Infinite @ 2 W	
Protection circuits	Load VSWR, over temperature	
Harmonics typ.	-15	dBc
Spurious typ.	-60	dBc
Modulation capability	100	%
Noise Figure typ.	10	dB
Intercept point 3 rd Order typ.		dBm
RF connectors	SMA female	
Cooling	by conduction	
Operating temperature Range	0 °C ... + 55	° C
Power Supply	13 - 15 DC +/- 5%	V
Dimensions (W x L x H)	BO16-1	mm
All data at room temperature + 22 °C, into 50 Ohms, subject to change without notice		

WWW.rfpa.com

Made in European Union

11/03/2002

R.F.P.A. S.A.

Parc d'activité de Fontaudin F33370 Artigues près Bordeaux

France Tél : +33 (0)5 56 86 85 84 Fax: + 33 (0) 5 56 86 55 56